74HC4067; 74HCT4067

16-channel analog multiplexer/demultiplexer

Rev. 7 — 2 June 2020

Product data sheet

1. General description

The 74HC4067; 74HCT4067 is a single-pole 16-throw analog switch (SP16T) suitable for use in analog or digital 16:1 multiplexer/demultiplexer applications. The switch features four digital select inputs (S0, S1, S2 and S3), sixteen independent inputs/outputs (Yn), a common input/output (Z) and a digital enable input (\overline{E}). When \overline{E} is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- Wide supply voltage range from 2.0 V to 10.0 V
- Input levels S0, S1, S2, S3 and Ē inputs:
 - For 74HC4067: CMOS level
 - For 74HCT4067: TTL level
- CMOS low power dissipation
- · High noise immunity
- Low ON resistance:
 - 80 Ω (typical) at V_{CC} = 4.5 V
 - 70 Ω (typical) at V_{CC} = 6.0 V
 - 60 Ω (typical) at V_{CC} = 9.0 V
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C
- · Typical 'break before make' built-in

3. Applications

- Analog multiplexing and demultiplexing
- · Digital multiplexing and demultiplexing
- Signal gating

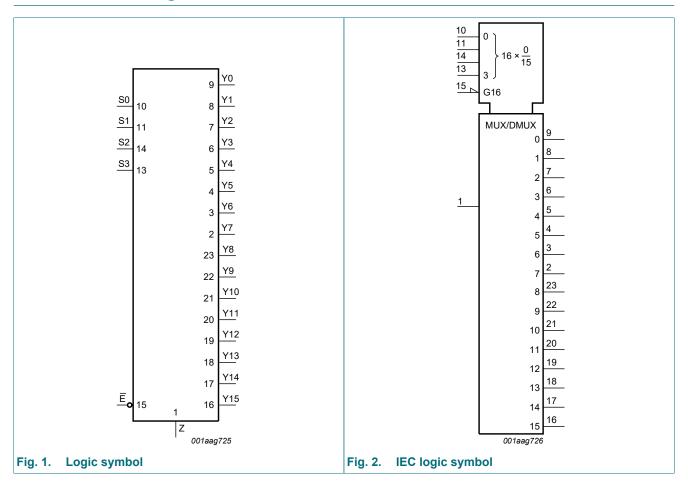


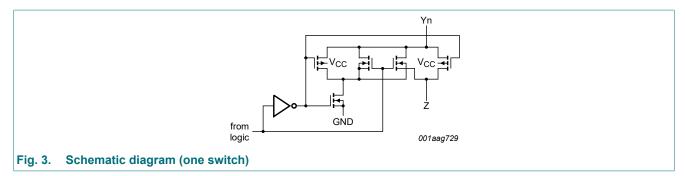
4. Ordering information

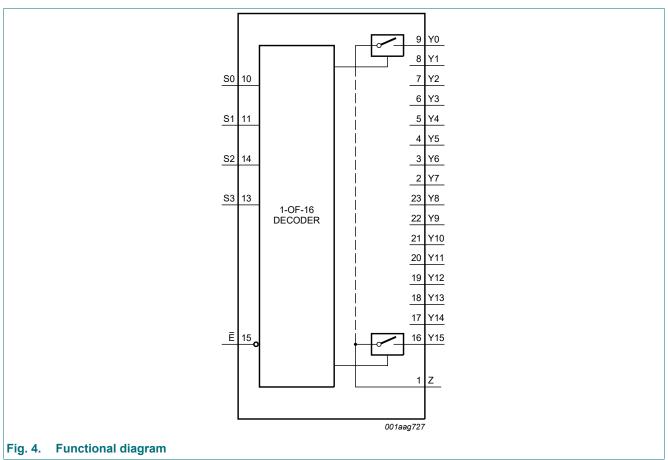
Table 1. Ordering information

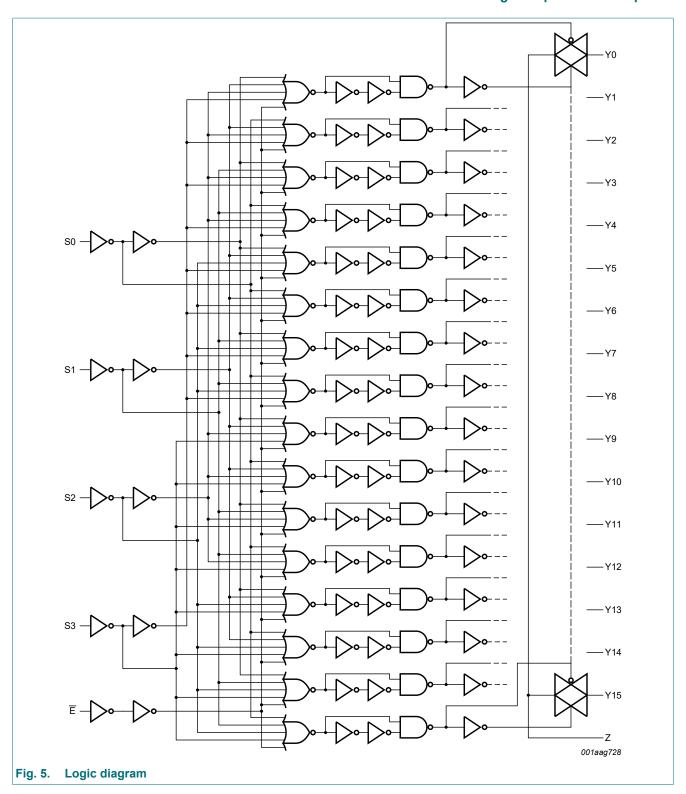
Type number	Package				
	Temperature range	Name	Description	Version	
74HC4067D	-40 °C to +125 °C	SO24	plastic small outline package; 24 leads;	SOT137-1	
74HCT4067D			body width 7.5 mm		
74HC4067DB	-40 °C to +125 °C	SSOP24	plastic shrink small outline package; 24 leads;	SOT340-1	
74HCT4067DB			body width 5.3 mm		
74HC4067PW	-40 °C to +125 °C	TSSOP24	plastic thin shrink small outline package; 24 leads;	SOT355-1	
74HCT4067PW			body width 4.4 mm		
74HC4067BQ	-40 °C to +125 °C	DHVQFN24	plastic dual in-line compatible thermal	SOT815-1	
74HCT4067BQ			enhanced very thin quad flat package; no leads; 24 terminals; body 3.5 x 5.5 x 0.85 mm		

5. Functional diagram





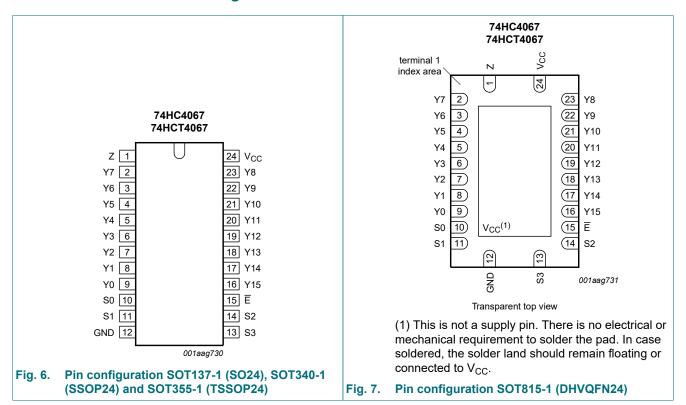




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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Z	1	common input or output
Y7, Y6, Y5, Y4, Y3, Y2, Y1, Y0, Y15, Y14, Y13, Y12, Y11, Y10, Y9, Y8	2, 3, 4, 5, 6, 7, 8, 9, 16, 17, 18, 19, 20, 21, 22, 23	independent input or output
S0, S1, S2, S3	10, 11, 14, 13	address input
GND	12	ground (0 V)
Ē	15	enable input (active LOW)
V _{CC}	24	supply voltage

7. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

Inputs					Channel ON
Ē	S3	S2	S1	S0	
L	L	L	L	L	Y0 to Z
L	L	L	L	Н	Y1 to Z
L	L	L	Н	L	Y2 to Z
L	L	L	Н	Н	Y3 to Z
L	L	Н	L	L	Y4 to Z
L	L	Н	L	Н	Y5 to Z
L	L	Н	Н	L	Y6 to Z
L	L	Н	Н	Н	Y7 to Z
L	Н	L	L	L	Y8 to Z
L	Н	L	L	Н	Y9 to Z
L	Н	L	Н	L	Y10 to Z
L	Н	L	Н	Н	Y11 to Z
L	Н	Н	L	L	Y12 to Z
L	Н	Н	L	Н	Y13 to Z
L	Н	Н	Н	L	Y14 to Z
L	Н	Н	Н	Н	Y15 to Z
Н	X	Х	Х	X	-

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage		[1]	-0.5	+11.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V		-	±20	mA
I _{SW}	switch current	$V_{SW} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I_{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	500	mW
Р	power dissipation	per switch		-	100	mW

^[1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Yn. In this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V_{CC} or GND.

For SOT340-1 (SSOP24) packages: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT355-1 (TSSOP24) package: P_{tot} derates linearly with 12.4 mW/K above 110 $^{\circ}\text{C}.$

For SOT815-1 (DHVQFN24) package: Ptot derates linearly with 15.0 mW/K above 117 °C.

^[2] For SOT137-1 (SO24) package: Ptot derates linearly with 16.2 mW/K above 119 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74HC4067			74HCT4067			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	10.0	4.5	5.0	5.5	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V _{SW}	switch voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
Δt/ΔV	input transition rise and fall	V _{CC} = 2.0 V	-	-	625	-	-	-	ns
	rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns
		V _{CC} = 10.0 V	-	-	31	-	-	-	ns
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C

10. Static characteristics

Table 6. R_{ON} resistance per switch for types 74HC4067 and 74HCT4067

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see Fig. 8.

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

Vos is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4067: V_{CC} - GND = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4067: V_{CC} - GND = 4.5 V.

Symbol	Parameter	Conditions		25	°C	-40 °C to +125 °C		Unit
				Тур	Max	Max (85 °C)	Max (125 °C)	
R _{ON(peak)}	ON resistance (peak)	V _{is} = V _{CC} to GND						
		V _{CC} = 2.0 V; I _{SW} = 100 μA	[1]	-	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		110	180	225	270	Ω
		V _{CC} = 6.0 V; I _{SW} = 1000 μA		95	160	200	240	Ω
	V _{CC} = 9.0 V; I _{SW} = 1000 μA 75 130 165	195	Ω					
R _{ON(rail)}	ON resistance (rail)	V _{is} = GND or V _{CC}						
		V_{CC} = 2.0 V; I_{SW} = 100 μ A	[1]	150	-	-	-	
		V _{CC} = 4.5 V; I _{SW} = 1000 μA		90	160	200	240	Ω
		V _{CC} = 6.0 V; I _{SW} = 1000 μA		80	140	175	210	Ω
		V _{CC} = 9.0 V; I _{SW} = 1000 μA		70	120	150	180	Ω
ΔR _{ON}	ON resistance mismatch	V _{is} = V _{CC} to GND						
	between channels	V _{CC} = 2.0 V	[1]	-	-	-	-	Ω
		V _{CC} = 4.5 V		9	-	-	-	Ω
		V _{CC} = 6.0 V		8	-	-	-	Ω
		V _{CC} = 9.0 V		6	-	-	-	Ω

^[1] At supply voltages (V_{CC} - GND) approaching 2 V, the analog switch ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

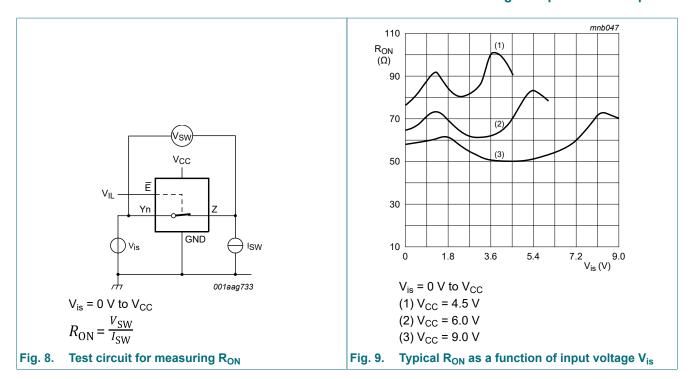


Table 7. Static characteristics 74HC4067

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C		_		'	
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4		V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1		V
		V _{CC} = 6.0 V	-	2.8	1.80	V
		V _{CC} = 9.0 V	-	4.3	2.70	V
I _I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±0.1	μΑ
		V _{CC} = 10.0 V	-	-	±0.2	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } Fig. 10$				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.8	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Fig. } 11}{\text{Fig. } 11}$	-	-	±0.8	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	8.0	μΑ
		V _{CC} = 10.0 V	-	-	16.0	μA
Cı	input capacitance		-	3.5	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.50	V
		V _{CC} = 4.5 V	-	-		V
		V _{CC} = 6.0 V	-	-	1.80	V
		V _{CC} = 9.0 V	-	-	2.70	V
ı	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	0.50 1.35 1.80 2.70 ±1.0 ±2.0 ±1.0 ±8.0 160 0.50 1.35 1.80 2.70 ±1.0 ±2.0	μΑ
		V _{CC} = 10.0 V	-	-		μΑ
S(OFF)	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } \frac{\text{Fig. } 10}{\text{Fig. } 10}$				
		per channel	-	-	0.50 ±1.0 ±8.0 ±8.0 ±8.0 0.50 1.35 1.80 2.70 ±1.0 ±8.0 ±8.0	μΑ
		all channels	-	-	±8.0	μΑ
S(ON)	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } Fig. 11$	-	-	±8.0	μΑ
CC	supply current	$V_1 = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	80.0	μA
		V _{CC} = 10.0 V	-	-	160	μA
T _{amb} = -4	0 °C to +125 °C					
√ _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	- 0.50 1.35 1.80 2.70 ±1.0 ±2.0 ±1.0 ±8.0 ±8.0 160 0.50 1.35 1.80 2.70 ±1.0 ±2.0	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
/ _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	1.35 1.80 2.70 ±1.0 ±2.0 ±1.0 ±8.0 160 0.50 1.35 1.80 2.70 ±1.0 ±2.0	V
		V _{CC} = 4.5 V	-	-		V
		V _{CC} = 6.0 V	-	-	1.80	V
		V _{CC} = 9.0 V	-	-	2.70	V
I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
S(OFF)	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } Fig. 10$				
		per channel	-	-	±1.0	μA
		all channels	-	-	±8.0	μA
S(ON)	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - \text{GND}; \text{ see } Fig. 11$	-	-		μA
СС	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		V _{CC} = 6.0 V	-	-	160	μA
		1 00 010 1			160	

Table 8. Static characteristics 74HCT4067

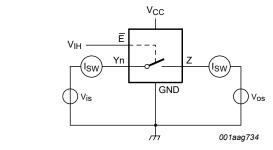
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

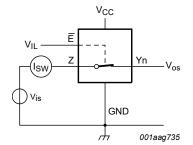
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 5.5 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - GND; see Fig. 10				
		per channel	-	-	±0.1	μΑ
		all channels	-	-	±0.8	μΑ
I _{S(ON)}	ON-state leakage current	V_{CC} = 5.5 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - GND; see Fig. 11	-	-	±0.8	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V	-	-	8.0	μA
ΔI _{CC}	additional supply current	per input pin; $V_1 = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V				
- - amb = -40		pin E	-	60	216	μΑ
		pin Sn	-	50	180	μΑ
C _I	input capacitance		-	3.5	-	pF
T _{amb} = -40	°C to +85 °C		'			
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 5.5 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - GND; see Fig. 10				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±8.0	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 5.5 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - GND; see Fig. 11	-	-	±8.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V	-	-	80.0	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V				
		pin Ē	-	-	270	μA
		pin Sn	-	-	225	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40	°C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
lį	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 5.5 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - GND; see Fig. 10				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±8.0	μΑ
I _{S(ON)}	ON-state leakage current	V_{CC} = 5.5 V; V_I = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - GND; see Fig. 11	-	-	±8.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = GND$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V	-	-	160	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V				
		pin Ē	-	-	294	μΑ
		pin Sn	-	-	245	μΑ



 $V_{is} = V_{CC}$ and $V_{os} = GND$ $V_{is} = GND$ and $V_{os} = V_{CC}$

Fig. 10. Test circuit for measuring OFF-state leakage current



 V_{is} = V_{CC} and V_{os} = open V_{is} = GND and V_{os} = open

Fig. 11. Test circuit for measuring ON-state leakage current

11. Dynamic characteristics

Table 9. Dynamic characteristics 74HC4067

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF unless specified otherwise; for test circuit see Fig. 14.

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		25	°C	-40 °C to	+125 °C	Unit
				Тур	Max	Max (85 °C)	Max (125 °C)	
t _{pd}	propagation delay	Yn to Z; see Fig. 12	[1][2]					
		V _{CC} = 2.0 V		25	75	95	110	ns
		V _{CC} = 4.5 V		9	15	19	22	ns
		V _{CC} = 6.0 V		7	13	16	19	ns
		V _{CC} = 9.0 V		5	9	11	14	ns
		Z to Yn						
		V _{CC} = 2.0 V		18	60	75	90	ns
		V _{CC} = 4.5 V		6	12	15	18	ns
		V _{CC} = 6.0 V		5	10	13	15	ns
		V _{CC} = 9.0 V		4	8	10	12	ns
off	turn-off time	E to Yn; see Fig. 13	[3]					
		V _{CC} = 2.0 V		74	250	315	375	ns
		V _{CC} = 4.5 V		27	50	63	75	ns
		V _{CC} = 5.0 V; C _L = 15 pF		27	-	-	75 -	ns
		V _{CC} = 6.0 V		22	43	54	64	ns
		V _{CC} = 9.0 V		20	38	48	64 57	ns
		Sn to Yn						
		V _{CC} = 2.0 V		83	250	315	375	ns
		V _{CC} = 4.5 V		30	50	63	75	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		29	-	-	-	ns
		V _{CC} = 6.0 V		24	43	54	64	ns
		V _{CC} = 9.0 V		21	38	48	57	ns
		E to Z						
		V _{CC} = 2.0 V		85	275	345	415	ns
		V _{CC} = 4.5 V		31	55	69	83	ns
		V _{CC} = 6.0 V		25	47	59	71	ns
		V _{CC} = 9.0 V		24	42	53	63	ns
		Sn to Z						
		V _{CC} = 2.0 V		94	290	365	435	ns
		V _{CC} = 4.5 V		34	58	73	87	ns
		V _{CC} = 6.0 V		27	47	62	74	ns
		V _{CC} = 9.0 V		25	45	56	68	ns

Symbol	Parameter	Conditions	25	°C	-40 °C to	+125 °C	Unit
			Тур	Max	Max (85 °C)	Max (125 °C)	
t _{on}	turn-on time	Ē to Yn; see Fig. 13 [4]					
		V _{CC} = 2.0 V	80	275	345	415	ns
		V _{CC} = 4.5 V	29	55	69	83	ns
		V _{CC} = 5.0 V; C _L = 15 pF	26	-	-	-	ns
		V _{CC} = 6.0 V	23	47	59	71	ns
		V _{CC} = 9.0 V	17	42	53	63	ns
		Sn to Yn					
		V _{CC} = 2.0 V	88	300	375	450	ns
		V _{CC} = 4.5 V	32	60	75	90	ns
		V _{CC} = 5.0 V; C _L = 15 pF	29	-	-	-	ns
		V _{CC} = 6.0 V	26	51	64	77	ns
		V _{CC} = 9.0 V	18	45	56	68	ns
		E to Z					
		V _{CC} = 2.0 V	85	275	345	415	ns
		V _{CC} = 4.5 V	31	55	69	83	ns
		V _{CC} = 6.0 V	25	47	59	71	ns
		V _{CC} = 9.0 V	18	42	53	63	ns
		Sn to Z					
		V _{CC} = 2.0 V	94	300	375	450	ns
		V _{CC} = 4.5 V	34	60	75	90	ns
		V _{CC} = 6.0 V	27	51	64	77	ns
		V _{CC} = 9.0 V	19	45	56	68	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC} [5]	29	-	-	-	pF

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$$
 where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

 t_{pd} is the same as t_{PHL} and t_{PLH} . Due to higher Z terminal capacitance (16 switches versus 1) the delay figures to the Z terminal are higher than those to the Y terminal.

^[3] t_{on} is the same as t_{PHZ} and t_{PLZ} .

^[4]

 $t_{\rm off}$ is the same as $t_{\rm PZH}$ and $t_{\rm PZL}$. $C_{\rm PD}$ is used to determine the dynamic power dissipation ($P_{\rm D}$ in μW).

Table 10. Dynamic characteristics 74HCT4067

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF unless specified otherwise; for test circuit see Fig. 14.

*V*_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		25	°C	-40 °C to	Unit	
				Тур	Max	Max (85 °C)	Max (125 °C)	
t _{pd}	propagation delay	Yn to Z; see Fig. 12	[1][2]					
		V _{CC} = 4.5 V		9	15	19	22	ns
		Z to Yn						
		V _{CC} = 4.5 V		6	12	15	18	ns
t _{off}	turn-off time	E to Yn; see Fig. 13	[3]					
		V _{CC} = 4.5 V		26	55	69	83	ns
		V _{CC} = 5.0 V; C _L = 15 pF		26	-	-	-	ns
		Sn to Yn						
		V _{CC} = 4.5 V		31	55	69	83	ns
		V _{CC} = 5.0 V; C _L = 15 pF		30	-	-	-	ns
		E to Z						
		V _{CC} = 4.5 V		30	60	75	90	ns
		Sn to Z						
		V _{CC} = 4.5 V		35	60	75	90	ns
t _{on}	turn-on time	E to Yn; see Fig. 13	[4]					
		V _{CC} = 4.5 V		32	60	75	90	ns
		V _{CC} = 5.0 V; C _L = 15 pF		32	-	-	-	ns
		Sn to Yn						
		V _{CC} = 4.5 V		35	60	75	90	ns
		V _{CC} = 5.0 V; C _L = 15 pF		33	-	-	-	ns
		E to Z						
		V _{CC} = 4.5 V		38	65	81	98	ns
		Sn to Z						
		V _{CC} = 4.5 V		38	65	81	98	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to $(V_{CC} - 1.5 V)$	[5]	29	-	-	-	pF

- t_{pd} is the same as t_{PHL} and t_{PLH} . Due to higher Z terminal capacitance (16 switches versus 1) the delay figures to the Z terminal are higher than those to the Y terminal.
- t_{on} is the same as t_{PHZ} and t_{PLZ} . [3]
- t_{off} is the same as t_{PZH} and t_{PZL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

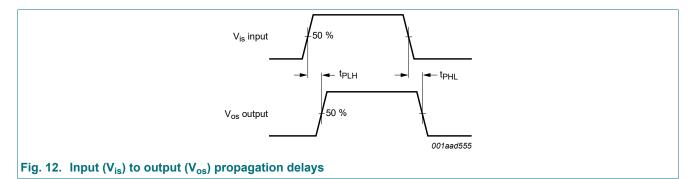
 $\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

11.1. Waveforms and test circuit



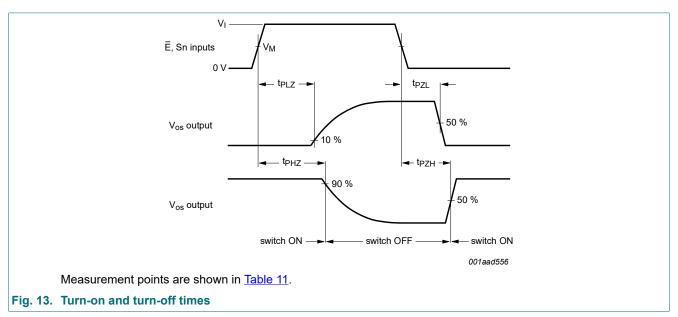
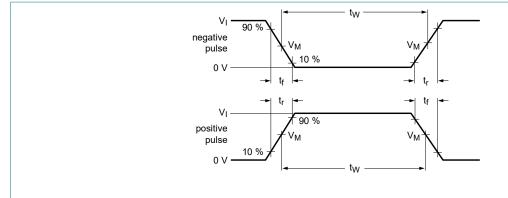
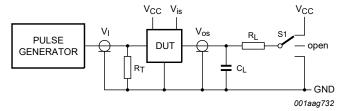


Table 11. Measurement points

Туре	V _I	V _M
74HC4067	V _{CC}	0.5V _{CC}
74HCT4067	3.0 V	1.3 V





Test data is given in Table 12.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

S1 = Test selection switch.

Fig. 14. Test circuit for measuring switching times

Table 12. Test data

Test	Input		Output	S1 position			
	Control E	Address Sn Switch Yn (Z)		t _r , t _f	Switch Z (Yn)		
	V _I [1]	V _I [1]	V _{is}		CL	R _L	
t _{PHL} , t _{PLH}	GND	GND or V _{CC}	GND to V _{CC}	6 ns	50 pF	-	open
t _{PHZ} , t _{PZH}	GND to V _{CC}	GND to V _{CC}	V _{CC}	6 ns	50 pF, 15 pF	1 kΩ	GND
t _{PLZ} , t _{PZL}	GND to V _{CC}	GND to V _{CC}	GND	6 ns	50 pF, 15 pF	1 kΩ	V _{CC}

[1] For 74HCT4067: maximum input voltage $V_I = 3.0 \text{ V}$.

12. Additional dynamic characteristics

Table 13. Additional dynamic characteristics

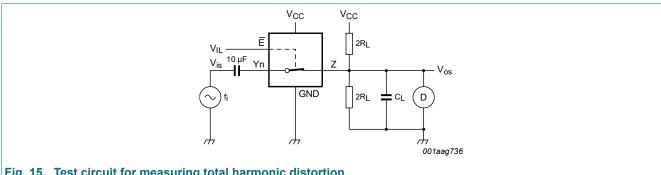
Recommended conditions and typical values; GND = 0 V.

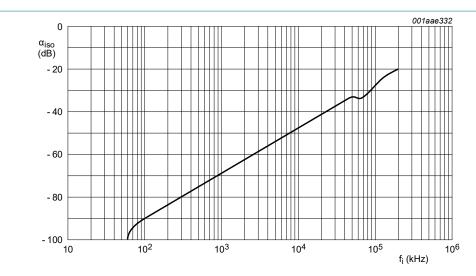
 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

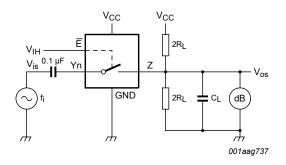
Symbol	Parameter	Conditions		Unit		
			Min	Тур	Max	
THD	total harmonic distortion	R_L = 10 kΩ; C_L = 50 pF; see <u>Fig. 15</u>				
		f _i = 1 kHz				
		V _{CC} = 4.5 V; V _{is(p-p)} = 4.0 V	-	0.04	-	%
		V _{CC} = 9.0 V; V _{is(p-p)} = 8.0 V	-	0.02	-	%
		f _i = 10 kHz				
		V _{CC} = 4.5 V; V _{is(p-p)} = 4.0 V	-	0.12	-	%
		V _{CC} = 9.0 V; V _{is(p-p)} = 8.0 V	-	0.06	-	%
α _{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $C_L = 50 pF$; see <u>Fig. 16</u> [1]			
		V _{CC} = 4.5 V	-	-50	-	dB
		V _{CC} = 9.0 V	-	-50	-	dB
f _(-3dB)	-3 dB frequency response	$R_L = 50 \Omega$; $C_L = 10 pF$; see <u>Fig. 17</u> [2]]			
		V _{CC} = 4.5 V	-	90	-	MHz
		V _{CC} = 9.0 V	-	100	-	MHz
C _{sw}	switch capacitance	independent pins Y	-	5	-	pF
		common pin Z	-	45	-	pF

- Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
- Adjust input voltage V_{is} to 0 dBm level at V_{os} for f_i = 1 MHz (0 dBm = 1 mW into 50 Ω). After set-up, f_i is increased to obtain a reading of -3 dB at Vos.





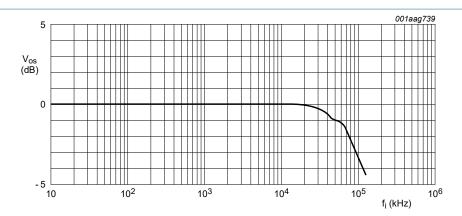
a. Isolation (OFF-state)



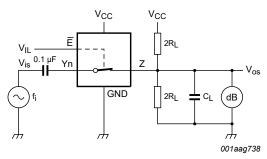
b. Test circuit

 V_{CC} = 4.5 V; GND = 0 V; R_L = 600 $\Omega;$ R_{source} = 1 $k\Omega.$

Fig. 16. Isolation (OFF-state) as a function of frequency



a. Typical -3 dB frequency response



b. Test circuit

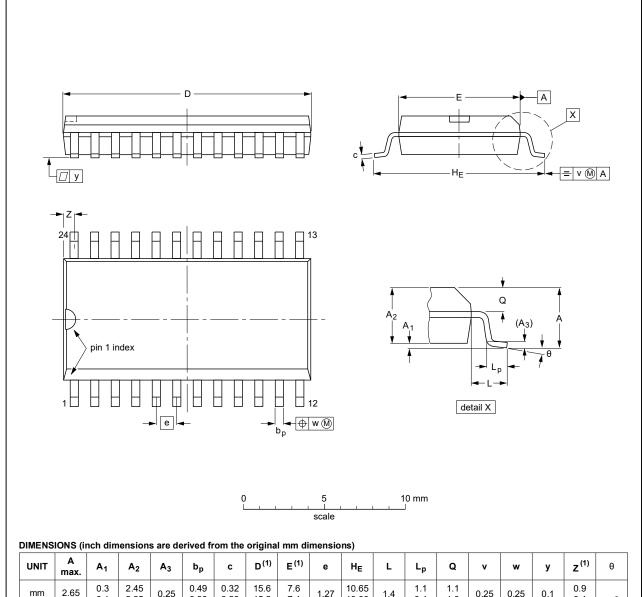
 V_{CC} = 4.5 V; GND = 0 V; R_L = 50 Ω ; R_{source} = 1 k Ω .

Fig. 17. -3 dB frequency response

13. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	V	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT137-1	075E05	MS-013				99-12-27 03-02-19

Fig. 18. Package outline SOT137-1 (SO24)

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1

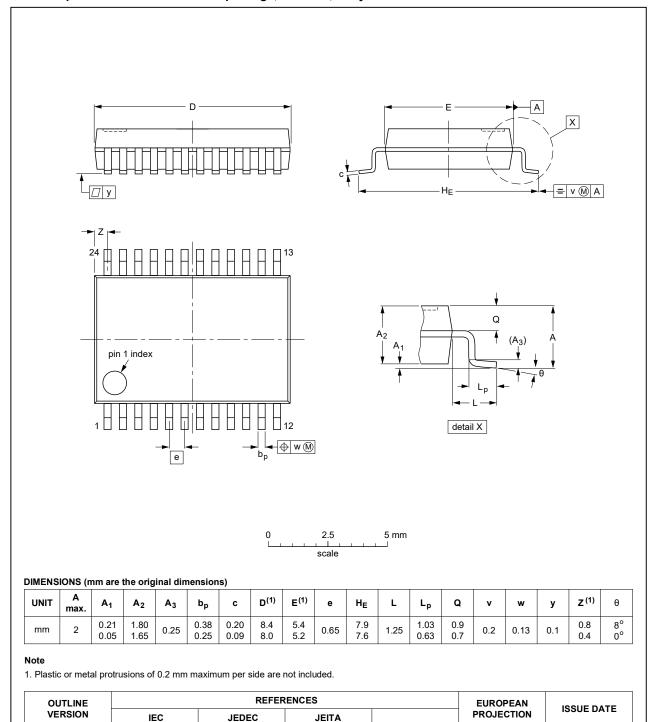


Fig. 19. Package outline SOT340-1 (SSOP24)

MO-150

SOT340-1

99-12-27

03-02-19

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1

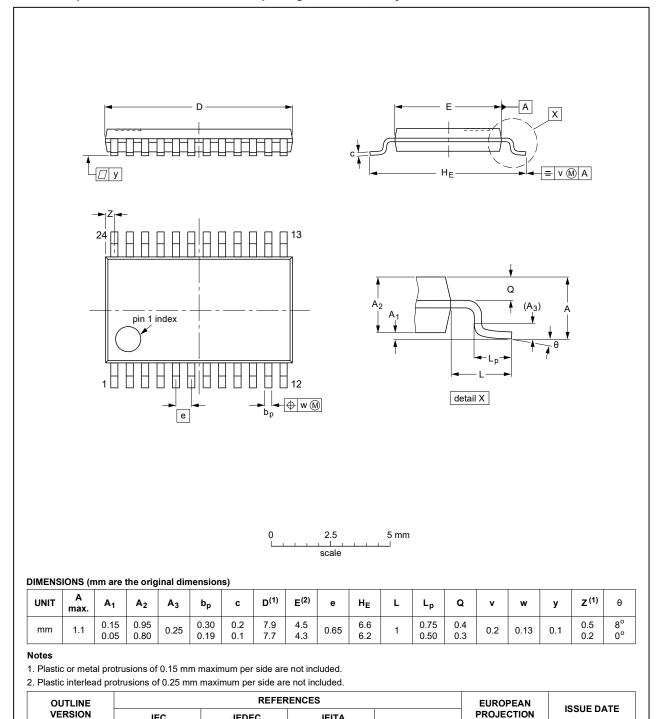


Fig. 20. Package outline SOT355-1 (TSSOP24)

SOT355-1

IEC

JEDEC

MO-153

JEITA

99-12-27

03-02-19

DHVQFN24: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body $3.5 \times 5.5 \times 0.85$ mm

SOT815-1

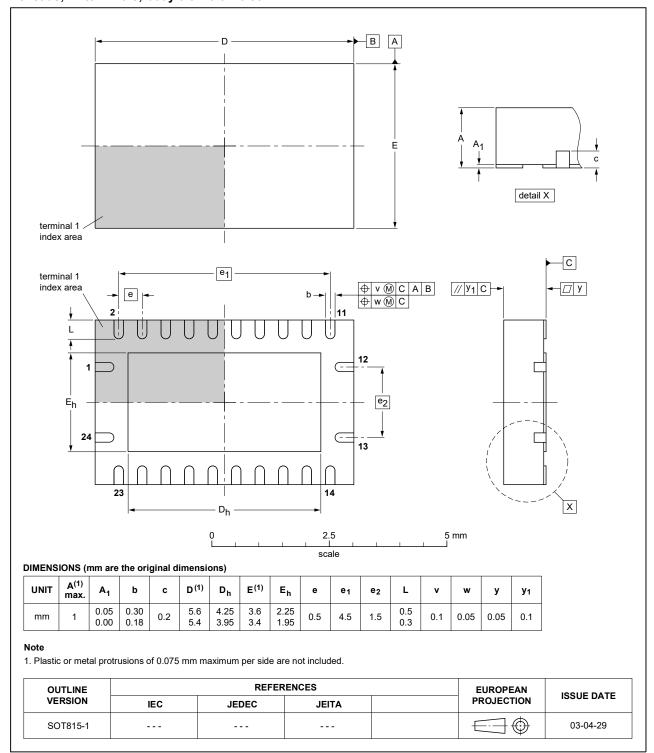


Fig. 21. Package outline SOT815-1 (DHVQFN24)

14. Abbreviations

Table 14. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 15. Revision history

	Table 15. Revision history								
Document ID	Release date	Data sheet status	Change notice	Supersedes					
74HC_HCT4067 v.7	20200602	Product data sheet	-	74HC_HCT4067 v.6					
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines Nexperia. Legal texts have been adapted to the new company name where appropriate. Section 2 updated. Table 4: Derating values for P_{tot} total power dissipation have been updated. 								
74HC_HCT4067 v.6	20150522	Product data sheet	-	74HC_HCT4067 v.5					
Modifications:		74HC4067N and 74HCT4067 Figure note $V_{is} = 0 \text{ V to } (V_{CC}\text{-G})$	` '						
74HC_HCT4067 v.5	20111213	Product data sheet	-	74HC_HCT4067 v.4					
Modifications:	 Legal pages up 	pdated.							
74HC_HCT4067 v.4	20110518	Product data sheet	-	74HC_HCT4067 v.3					
74HC_HCT4067 v.3	20071015	Product data sheet	-	74HC_HCT4067_CNV v.2					
74HC_HCT4067_CNV v.2	19970901	Product specification	-	-					

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition		
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.		
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.		
Product [short] data sheet	Production	This document contains the product specification.		

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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